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|  | <h2 style="color: red;">FQP20N06L</h2> |
| | <p>Hersteller-Teilenummer: FQP20N06L</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 21A TO-220</p> <p>Datenblätter: 1.FQP20N06L.pdf 2.FQP20N06L.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 40548 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | FQP20N06L |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 60V 21A TO-220 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 40548 pcs Stock |
| Hersteller Standard Vorlaufzeit | 6 Weeks |
| detaillierte Beschreibung | N-Channel 60V 21A (Tc) 53W (Tc) Through Hole TO- |
| Serie | QFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 53W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 21A (Tc) |
| Rds On (Max) @ Id, Vgs | 55 mOhm @ 10.5A, 10V |
| VGS (th) (Max) @ Id | 2.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 13nC @ 5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 630pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tube |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

FQP20N06L ist neu im Original, Suche FQP20N06L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP20N06L AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP20N06L: Info@Y-IC.com

Sie können auch interessiert sein:

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|  <p>FQP20N06TSTU Fairchild/ON Semiconductor MOSFET N-CH 60V 20A TO-220</p> |  <p>FQP20N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A TO-220</p> |  <p>FQP20N06TSTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A TO-220</p> |  <p>FQP20N80 FAIRCHILD FAIRCHILD TO-220</p> |
|  <p>FQP20N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 20A TO-220</p> |  <p>FQP20N06L Fairchild/ON Semiconductor MOSFET N-CH 60V 21A TO-220</p> |  <p>FQP1N60C VB FQP1N60C VB</p> |  <p>FQP1P50 AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 1.5A TO-220</p> |

heiße Teile

Mehr

| | | | | |
|--------------|----------------|----------------|--------------|--------------|
| ⊗ FQP17N08L | ↔ FQP17N08L | ⇒ FQP17N40 | D FQP17N40 | ↗ FQP17P06 |
| ⊕ FQP17P06 | ⊗ FQP17P10 | D FQP17P10 | ⇒ FQP18N20V2 | ↗ FQP18N20V2 |
| ⊗ FQP18N50V2 | ⊕ FQP18N50V2 | ⊗ FQP19N10 | ↔ FQP19N10 | ↗ FQP19N10L |
| D FQP19N10L | ⊗ FQP19N20 | ⊕ FQP19N20 | ⊗ FQP19N20C | ↗ FQP19N20C |
| ⇒ FQP19N20L | ↔ FQP19N20L | ⊗ FQP1N60C | ⊕ FQP20N06 | ↗ FQP20N06 |
| ↔ FQP20N06L | ⇒ FQP20N06TSTU | D FQP20N06TSTU | ⊗ FQP20N60 | ⊕ FQP22N30 |
| ⊗ FQP22N30 | D FQP22P10 | ⇒ FQP22P10 | ↔ FQP24N08 | ↗ FQP24N08 |
| ⊕ FQP24N40 | ⊗ FQP27N25 | ↔ FQP27N25 | ⇒ FQP27N60 | ↗ FQP27P06 |
| ⊗ FQP27P06 | ⊕ FQP2N60B | ⊗ FQP2N60C | D FQP2N60C | ↗ FQP2N65C |
| ↔ FQP30N06 | ⊗ FQP30N06 | ⊕ FQP30N06L | ⊗ FQP30N06L | ↗ FQP32N12V2 |

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